

## **Excellent Integrated System Limited**

Stocking Distributor

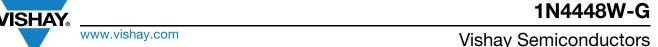
Click to view price, real time Inventory, Delivery & Lifecycle Information:

<u>Vishay Semiconductor/Diodes Division</u> 1N4448W-G3-18

For any questions, you can email us directly: <a href="mailto:sales@integrated-circuit.com">sales@integrated-circuit.com</a>

# Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of 1N4448W-G3-18 - DIODE GEN PURP 75V 150MA SOD123

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



## **Small Signal Fast Switching Diode**



#### **FEATURES**

- Silicon epitaxial planar diode
- Fast switching diode
- AEC-Q101 qualified
- Base P/N-G3 green, commercial grade
- Material categorization:
   For definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>





ROHS
COMPLIANT
HALOGEN
FREE
GREEN
(5-2008)

#### **MECHANICAL DATA**

Case: SOD-123

Weight: approx. 9.4 mg
Packaging codes/options:

18/10K per 13" reel (8 mm tape), 10K/box 08/3K per 7" reel (8 mm tape), 15K/box

PARTS TABLE				
PART	ORDERING CODE	INTERNAL CONSTRUCTION	TYPE MARKING	REMARKS
1N4448W-G	1N4448W-G3-08 or 1N4448W-G3-18	Single diode	AJ	Tape and reel

ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V <sub>R</sub>	75	V
Repetitive peak reverse voltage		V <sub>RRM</sub>	100	V
Average rectified current half wave rectification with resistive load (1)	f ≥ 50 Hz	I <sub>F(AV)</sub>	150	mA
Surge current	t < 1 s and T <sub>j</sub> = 25 °C	I <sub>FSM</sub>	500	mA
Power dissipation (1)		P <sub>tot</sub>	500	mW

THERMAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Thermal resistance junction to ambient air (1)		R <sub>thJA</sub>	350	K/W	
Junction temperature		Tj	150	°C	
Storage temperature		T <sub>stg</sub>	- 65 to + 150	°C	
Operating temperature		T <sub>op</sub>	- 55 to + 150	°C	

#### Note

<sup>(1)</sup> Valid provided that electrodes are kept at ambient temperature.

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## Vishay Semiconductors

1N4448W-G

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Command valtage	I <sub>F</sub> = 5 mA	V <sub>F</sub>	0.62		0.72	V
Forward voltage	I <sub>F</sub> = 100 mA	V <sub>F</sub>			1	V
	V <sub>R</sub> = 20 V	I <sub>R</sub>			25	nA
Leakage current	V <sub>R</sub> = 75 V	I <sub>R</sub>			5	μΑ
	V <sub>R</sub> = 20 V, T <sub>J</sub> = 150 °C	I <sub>R</sub>			50	μΑ
Capacitance	$V_F = V_R = 0 V$				4	pF
Reverse recovery time	$I_F = 10 \text{ mA}, i_R = 1 \text{ mA}, V_R = 6 \text{ V}, R_L = 100 \Omega$	t <sub>rr</sub>			4	ns

#### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

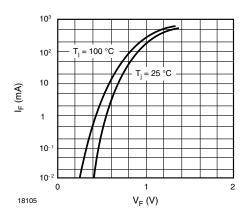


Fig. 1 - Forward Characteristics

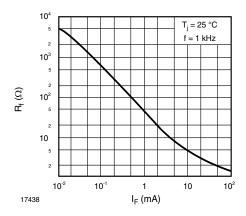


Fig. 2 - Dynamic Forward Resistance vs. Forward Current

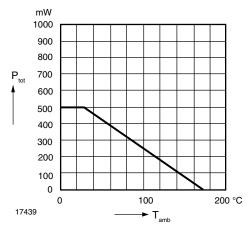


Fig. 3 - Admissible Power Dissipation vs. Ambient Temperature

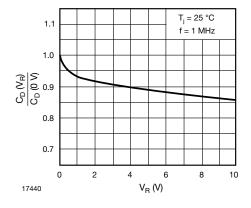


Fig. 4 - Relative Capacitance vs. Reverse Voltage

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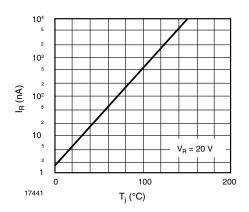


Fig. 5 - Leakage Current vs. Junction Temperature

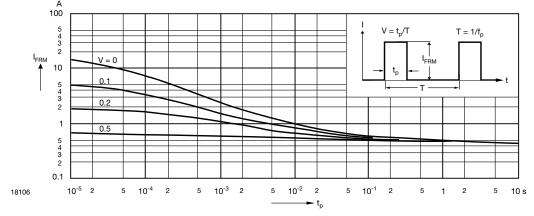


Fig. 6 - Admissible Repetitive Peak Forward Current vs. Pulse Duration

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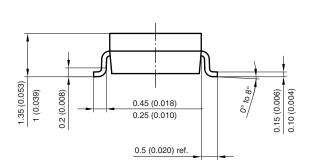
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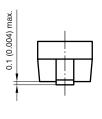


#### 1N4448W-G

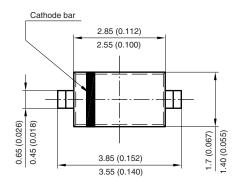
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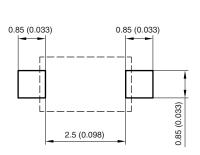
#### PACKAGE DIMENSIONS in millimeters (inches): SOD-123





Mounting Pad Layout





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